

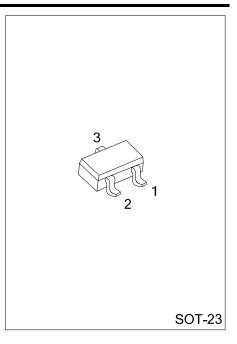
UNISONIC TECHNOLOGIES CO., LTD

UP2518 **Preliminary** PNP TRANSISTOR

LOW $V_{CE(SAT)}$ PNP SILICON POWER TRANSISTORS

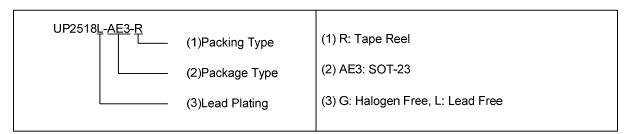
FEATURES

- *Extremely low collector-emitter saturation voltage V_{CE(SAT)} and corresponding extremely low equivalent on-resistance R_{CE(SAT)} $(97m\Omega \text{ at } 1.5A)$
- * High collector current capability(1.5A)
- * High peak pulse current up to 6A
- * High collector current gain

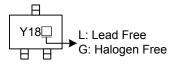


ORDERING INFORMATION

Ordering Number		Dookogo	Pin Assignment			Dooking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
UP2518L-AE3-R	UP2518G-AE3-R	SOT-23	Е	В	С	Tape Reel	



MARKING



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ABSOLUTE MAXIMUM RATING (Ta= 25°C, unless otherwise stated)

PARAMETER		RATINGS	UNIT
Collector-Base Voltage		-20	V
Collector-Emitter Voltage		-20	V
Emitter-Base Voltage		-5	V
Peak Pulse Current (Note 2)		-6	Α
Continuous Collector Current	I _C	-1.5	Α
Base Current	Ι _Β	-500	mA
Power Dissipation (Note 3) T _a =25°	C P _D	625	mW
Junction Temperature	TJ	+150	°C
Storage Temperature	T _{STG}	-55~+150	°C

- Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.
 - 2. Pulse width=300µs. Duty cycle≤2%
 - 3. Assume the device is mounted and measured on a ceramic substrate15x15x0.6mm

■ ELECTRICAL CHARACTERISTICS (T_a= 25°C, unless otherwise stated)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Base Breakdown Voltage	BV _{CBO}	I _C = -100μA	-20	-65		V
Collector-Emitter Breakdown Voltage	BV_{CEO}	I _C = -10mA (Note)	-20	-55		V
Emitter-Base Breakdown Voltage	BV_{EBO}	I _E = -100μA	-5	-8.8		V
Collector Cut-Off Current	I _{CBO}	V _{CB} = -15V			-100	nA
Emitter Cut-Off Current	I _{EBO}	V _{EB} = -4V			-100	nA
Collector Emitter Cut-Off Current	I _{CES}	V _{CES} = -15V			-100	nA
	` ′	I _C = -100mA, I _B = -10mA (Note)		-16	-40	mV
Collector-Emitter Saturation Voltage		I _C = -1A, I _B = -20mA (Note)		-130	-200	mV
		I _C = -1.5A, I _B = -50mA (Note)		-145	-220	mV
Base-Emitter Saturation Voltage	$V_{BE(SAT)}$	I _C = -1.5A, I _B = -50mA (Note)		-0.87	-1.0	V
Base-Emitter Turn-On Voltage	$V_{BE(ON)}$	V _{CE} = -2V, I _C = -2A (Note)		-0.81	-1.0	V
	h _{FE}	V_{CE} = -2V, I_{C} = -10mA (Note)	300	475		
		V _{CE} = -2V, I _C = -100mA (Note)	300	450		
DC Current Gain		V _{CE} = -2V, I _C = -2A, (Note)	150	230		
		V _{CE} = -2V, I _C = -4A, (Note)	35	70		
		V _{CE} = -2V, I _C = -6A, (Note)	15	30		
Transition Frequency	f_{T}	V _{CE} =-10V , I _C = -50mA, f=100MHz	150	180		MHZ
Output Capacitance	Сов	V _{CB} = -10V, f=1MHz		21	30	pF
Turn-On Time	t _(ON)	V _{CC} = -10V, I _C = -1A		40		ns
Turn-Off Time	t _(OFF)	I _{B1} = I _{B2} = -20mA		670		ns

Note: Measured under pulsed conditions. Pulse width=300µs. Duty cycle≤2%

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